## Features

## QFN12L (3 x 3 mm )

- Low Insertion Loss : 0.8 dB @ 2.5 GHz

$$
1.0 \mathrm{~dB} @ 4.9 \text { to } 6.0 \mathrm{GHz}
$$

- High Isolation: 43 dB @ 2.5 GHz

36 dB @ 4.9 to 6.0 GHz

- Low DC Power Consumption
- Miniature QFN12L (3x3 mm) Plastic Lead (Pb) Free Package
- PHEMT process
- Lead Free and RoHS Compliant Version of
HWS411


## Description

The HWS415 is a GaAs PHEMT MMIC DPDT switch operating at DC-6 GHz in a low cost miniature QFN12L ( $3 \times 3 \mathrm{~mm}$ ) plastic lead ( Pb ) free package. The HWS415 features low insertion loss and high isolation up to 6 GHz with very low DC power consumption. This switch can be used in IEEE 802.11a/b/g WLAN systems for combination of transmit/receive and antenna diversity functions.

## Electrical Specifications at $25^{\circ} \mathrm{C}$ with $0,+3 \mathrm{~V}$ Control Voltages

| Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss | $\begin{aligned} & \text { 0.1-6.0 GHz } \\ & 2.4-2.5 \mathrm{GHz} \\ & 4.9-6.0 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 1.0 \\ & 0.8 \\ & 1.0 \end{aligned}$ | 1.3 | dB <br> dB <br> dB |
| Isolation (on/off or off/on) | $\begin{aligned} & \text { 0.1-6.0 GHz } \\ & 2.4-2.5 \mathrm{GHz} \\ & 4.9-6.0 \mathrm{GHz} \end{aligned}$ | 26 | $\begin{aligned} & 36 \\ & 43 \\ & 36 \end{aligned}$ |  | dB <br> dB <br> dB |
| Isolation (off/off) | $\begin{aligned} & 2.4-2.5 \mathrm{GHz} \\ & 4.9-6.0 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 10 \\ & 17 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \end{aligned}$ |
| Return Loss | $\begin{aligned} & \text { 0.1-6.0 GHz } \\ & 2.4-2.5 \mathrm{GHz} \\ & 4.9-6.0 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 15 \\ & 20 \\ & 18 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ |
| Input Power for One dB Compression | 2.0-6.0 GHz |  | 30 |  | dBm |
| Second Harmonic | $\mathrm{Pin}=20 \mathrm{dBm}$ |  | -75 |  | dBc |
| Third Harmonic | Pin=20 dBm |  | -75 |  | dBc |
| Input Third Order Intermodulation Intercept Point | 20 dBm Per Tone @ 5.85 GHz |  | 45 |  | dBm |
| Switching Time |  |  | 50 |  | ns |
| Control Current |  |  | 5 | 100 | uA |

Note: All measurements made in a 50 ohm system with $0 /+3.0 \mathrm{~V}$ control voltages, unless otherwise specified.

Typical Performance Data with 8pF Capacitors @ $+25^{\circ} \mathrm{C}$

Insertion Loss vs Frequency


Isolation vs Frequency


## Return Loss vs Frequency



## Absolute Maximum Ratings

| Parameter | Absolute Maximum |
| :--- | :---: |
| RF Input Power | $+32 \mathrm{dBm} @+3 \mathrm{~V}$ |
| Control Voltage | +6 V |
| Operating Temperature | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

## Pin Out (Top View)



1. DC blocking capacitors $C_{B}=8 p F$ are required on all RF ports.
2. Exposed pad in the bottom must be connected to ground by via holes.
3. TX and RX ports can be used interchangeably.

## Logic Table for Switch On-Path

| VC1 | VC2 | ANT1-RX | ANT1-TX | ANT2-TX | ANT2-RX |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | 0 | On | Off | On | Off |
| 0 | 1 | Off | On | Off | On |
| 1 | 1 | Off | Off | Off | Off |
| 0 | 0 | Off | Off | Off | Off |

' 1 ' = +3V to +5V
' 0 ' $=0 \mathrm{~V}$ to +0.2 V

